NSN 5961-00-902-7475

A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-902-7475 **Inclosure Material:** Metal **Overall Length:** Between 0.330 inches and 0.505 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Overall Width Across Flats:** Between 0.544 inches and 0.562 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.5 gate trigger voltage, dc and 2.5 on-state voltage, dc **Current Rating Per Characteristic:** 10.00 amperes forward current, total rms nanoamperes and 150.00 milliamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 35.0 degrees celsius case **Special Features:** Internal junction configuration arrangement pnpn **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: